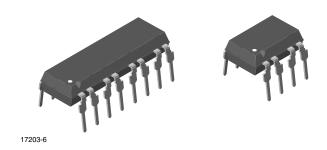
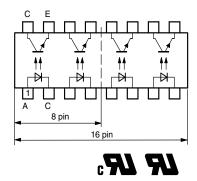




Vishay Semiconductors

Optocoupler, Phototransistor Output





DESCRIPTION

In the K827PH, K847PH parts each channel consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 8 pin (dual); 16 pin (quad) plastic dual inline package.

FEATURES

- DC isolation test voltage 5000 V_{RMS}
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





RoHS

APPLICATIONS

- Programmable logic controllers
- Modems
- Answering machines
- General applications

AGENCY APPROVALS

- UL
- cUL

LINKS TO ADDITIONAL RESOURCES



17203-7

ORDERING INFORMATION				
К 8	# 7	Р	н	DIP-8 / DIP-16
	PART NUMBER			7.62 mm
AGENCY CERTIFIED / PACKAGE			CTR (%)	
UL, cUL			50 to 600	
DIP-8			K827PH	
DIP-16			K847PH	

Note

• K827PH and K847PH are marked as K827P and K847P respectively



K827PH, K847PH

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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT						
Reverse voltage		V _R	6	V		
Forward current		I _F	60	mA		
Forward surge current	t _P ≤ 10 μs	I _{FSM}	1.5	А		
Power dissipation		P _{diss}	100	mW		
Junction temperature		Tj	125	°C		
OUTPUT						
Collector emitter voltage		V_{CEO}	70	V		
Emitter collector voltage		V _{ECO}	7	V		
Collector current		Ic	50	mA		
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I _{CM}	100	mA		
Power dissipation		P _{diss}	150	mW		
Junction temperature		Tj	125	°C		
COUPLER						
Total power dissipation		P _{tot}	250	mW		
Operating ambient temperature range		T _{amb}	-40 to +100	°C		
Storage temperature range		T _{stg}	-55 to +125	°C		
Soldering temperature (1)	2 mm from case, t ≤ 10 s	T _{sld}	260	°C		

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to wave profile for soldering conditions for through hole devices

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION SYMI		MIN.	TYP.	MAX.	UNIT	
INPUT	INPUT						
Forward voltage	I _F = 50 mA	V_{F}	-	1.25	1.6	V	
Junction capacitance	$V_R = 0 V, f = 1 MHz$	C _j	-	50	-	pF	
OUTPUT							
Collector emitter voltage	I _C = 100 μA	V_{CEO}	70	-	-	V	
Emitter collector voltage	I _E = 100 μA	V_{ECO}	7	-	-	V	
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I _{CEO}	-	-	100	nA	
COUPLER							
Collector emitter saturation voltage	I _F = 10 mA, I _C = 1 mA	V _{CEsat}	-	-	0.3	V	
Cut-off frequency	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}, R_L = 100 \Omega$	f _c	-	100	-	kHz	
Coupling capacitance	f = 1 MHz	C_k	-	0.3	-	pF	

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX.						UNIT	
1.71	V - 5 V I - 5 m A	K827PH	CTR	50	-	600	%
I _C /I _F	$V_{CE} = 5 \text{ V}, I_{F} = 5 \text{ mA}$	K847PH	CTR	50	-	600	%



K827PH, K847PH

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SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _d	-	3	-	μs	
Rise time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _r	-	3	-	μs	
Fall time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _f	-	4.7	-	μs	
Storage time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _s	-	0.3	-	μs	
Turn-on time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _{on}	-	6	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$ (see figure 1)	t _{off}	-	5	-	μs	
Turn-on time	V_S = 5 V, I_F = 10 mA, R_L = 1 k Ω (see figure 2)	t _{on}	-	9	-	μs	
Turn-off time	$V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega \text{ (see figure 2)}$	t _{off}	-	18	-	μs	

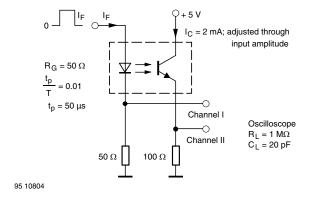


Fig. 1 - Test Circuit, Non-Saturated Operation

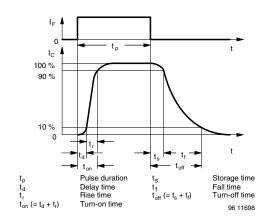


Fig. 3 - Switching Times

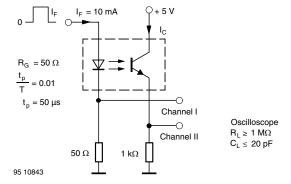


Fig. 2 - Test Circuit, Saturated Operation



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SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
Climatic classification	According to IEC 68 part 1		40 / 100 / 21				
Comparative tracking index		CTI	175				
Maximum rated withstanding isolation voltage	t = 1 min	V _{ISO}	4420	V _{RMS}			
Maximum transient isolation voltage		V _{IOTM}	10 000	V_{peak}			
Maximum repetitive peak isolation voltage		V _{IORM}	890	V_{peak}			
Isolation resistance	$V_{IO} = 500 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω			
isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω			
Output safety power		P _{SO}	400	mW			
Input safety current		I _{SI}	275	mA			
Safety temperature		T _S	175	°C			
Creepage distance			≥ 7	mm			
Clearance distance			≥ 7	mm			
Insulation thickness		DTI	≥ 0.4	mm			

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

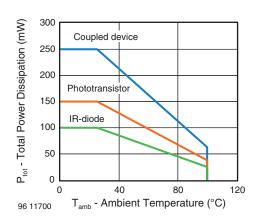


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

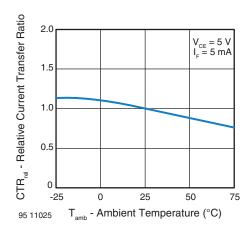


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

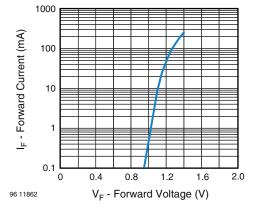


Fig. 5 - Forward Current vs. Forward Voltage

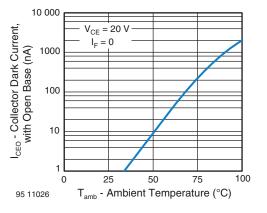


Fig. 7 - Collector Dark Current vs. Ambient Temperature

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.



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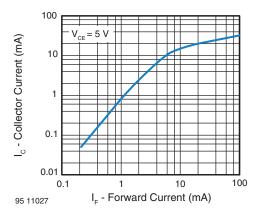


Fig. 8 - Collector Current vs. Forward Current

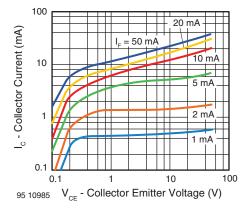


Fig. 9 - Collector Current vs. Collector Emitter Voltage

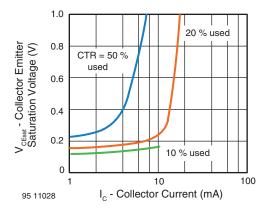


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

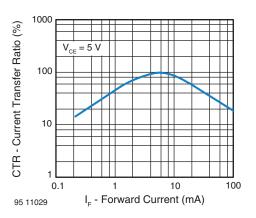


Fig. 11 - Current Transfer Ratio vs. Forward Current

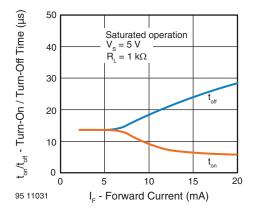


Fig. 12 - Turn-On / Turn-Off Time vs. Forward Current

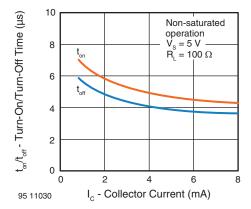


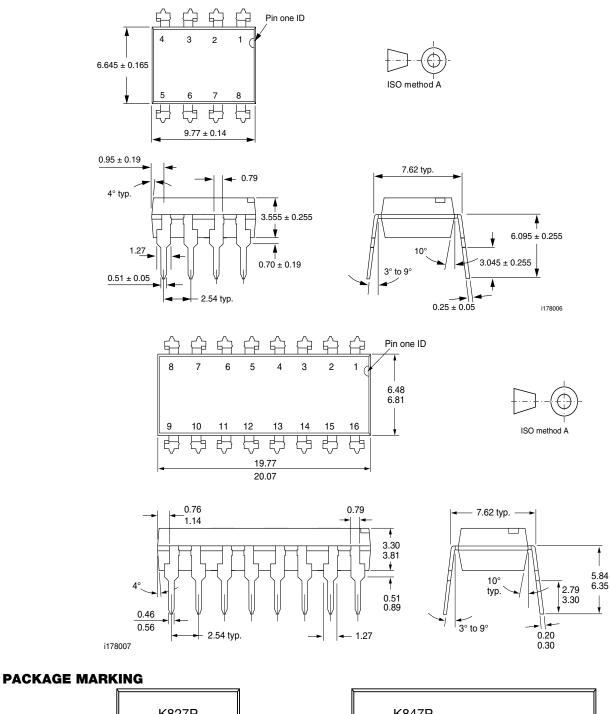
Fig. 13 - Turn-On / Turn-Off Time vs. Collector Current

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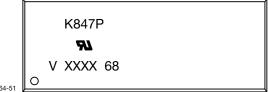


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PACKAGE DIMENSIONS in millimeters







Note

XXXX = LMC (lot marking code)





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